

## 1. Scope

The present specifications shall apply to an FML-G16S.

## 2. Outline

Type	Silicon Diode
Structure	Resin Molded
Applications	High Frequency Rectification

## 3. Flammability

UL94V-0(Equivalent)

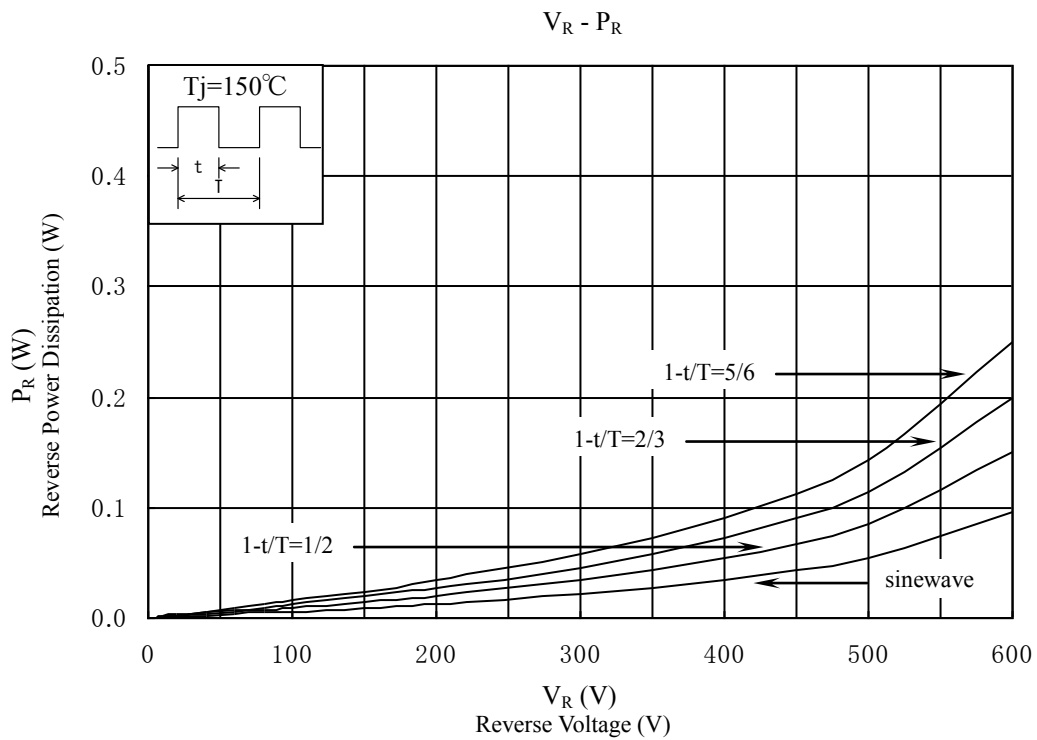
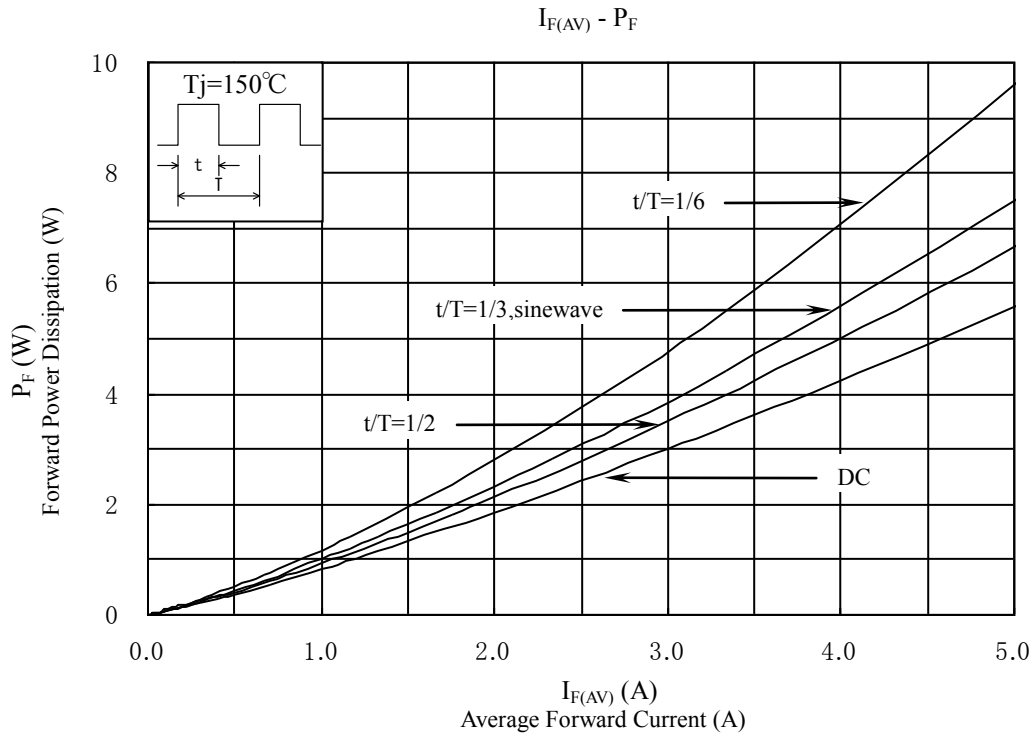
## 4. Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	$V_{RSM}$	V	600	
2	Peak Reverse Voltage	$V_{RM}$	V	600	
3	Average Forward Current	$I_{F(AV)}$	A	5.0	Refer to Derating of 7
4	Peak Surge Forward Current	$I_{FSM}$	A	50	10msec. Half sinewave, one shot
5	$I^2t$ Limiting Value	$I^2t$	$A^2s$	12.5	$1msec \leq t \leq 10msec$
6	Junction Temperature	$T_j$	$^{\circ}C$	-40~+150	
7	Storage Temperature	$T_{stg}$	$^{\circ}C$	-40~+150	
8	Dielectric Strength		kV	A.C. 1.0	Junction and case (1min.)

## 5. Electrical characteristics (Ta=25°C , unless otherwise specified)

No.	Item	Symbol	Unit	Value	Conditions
1	Forward Voltage Drop	$V_F$	V	1.5 max.	$I_F=5.0A$
2	Reverse Leakage Current	$I_R$	$\mu A$	100 max.	$V_R=V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H \cdot I_R$	$\mu A$	500 max.	$V_R=V_{RM}, T_j=150^{\circ}C$
4	Reverse Recovery Time	trr1	ns	50 max.	$I_F=I_{RP}=500mA$ 90% Recovery point, $T_j=25^{\circ}C$
		trr2	ns	35 max.	$I_F=500mA, I_{RP}=1A$ 75% Recovery point, $T_j=25^{\circ}C$
5	Thermal Resistance	$R_{th(j-c)}$	$^{\circ}C/W$	4.0 max.	Between Junction and case

6. Characteristics



7. Derating

